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RESEARCH ARTICLE

A New Simulation Method for Charcterization of Mechanical Properties of Nanomaterials

¹H. Arabshahi and ²G. R. Ebrahimi

¹Department of Physics, Ferdowsi University of Mashhad, Mashhad, Iran ²Department of Metalogy, Sabzevar Tarbiat Moallem University, Sabzevar, Iran Email: g.rebrahimi@yahoo.com

ABSTRACT

A new simulation method has been developed and used to model mechanical properties of materials at many different length scales, from the nanoscale where an atomic description is appropriate, through a mesoscale where dislocation based descriptions may be useful, to macroscopic length scales. In some materials, such as nanocrystalline metals, the range of length scales is compressed and a polycrystalline material may be simulated at the atomic scale. It is observed how the grain boundaries contribute actively to the deformation. At grain sizes below 5-10 nm deformation in the grain boundaries dominate over the traditional dislocation-based deformation mechanisms. This results in a reversal of the normal grain size dependence of the yield stress. It is shown that the material becomes softer when the grain size is reduced.

INTRODUCTION

Nanocrystalline metals are an attractive group of materials to model for many reasons. The materials are interesting from a technological point of view, but also from a theoretical point of view since the small grain size results in a "cut off" of the typical length scales of the phenomena and structures that may appear during the deformation process. This simplifies the deformation process and may possibly facilitate the development of theoretical models. Eventually, it may be possible to extend these models to the more complicated cases of coarse grained materials. For the smallest grain sizes (below approximately 5-10 nm) it becomes possible to model the deformation processes may then be studied directly. Nanocrystalline metals are metals with grain sizes on the nanometer scale, typical grain diameters range from 5 to 50 nanometers. These materials are of technological interest, mainly because their strength and hardness often are far above what is seen in coarse-grained metals. This is generally believed to be caused by the grain boundaries acting as barriers to dislocation motion: as the grain size is decreased, the number of grain boundaries increase and the dislocation motion becomes harder, leading to a harder material [2].

THE SIMULATION TECHNIQUE

We model the interactions between the atoms using a many-body potential known as the effective medium theory (EMT) [3-4]. It is very important that the interactions are modeled using a realistic many-body potential such as EMT, the embedded atom method or the Finnis-Sinclair model [5]. Pair potentials such as Lennard Jones are still seen used for simulating metals due to the lower computational burden. Although they give a good description of noble gas solid, they are not adequate for modeling the bonding in metallic systems. One symptom of this is seen in the elastic constants, all pair potentials result in materials that satisfies the Cauchy relations between the elastic constants ($C_{12} = C_{44}$ for cubic crystals), a relation that is far from true in most metals. In the simulations, the samples are deformed by slowly increasing the system size along the z axis while minimizing the energy with respect to all atomic coordinates and with respect to the box dimensions in the x and y directions. The minimization is done as a modified molecular dynamics simulation. After each time step the dot product between the momentum and the force is calculated for each atom. Any atom where the dot product is negative gets its momentum zeroed, as it is moving in a direction where the potential energy is increasing. This algorithm [6] is very efficient for this type of minimization. Before each time step the system is stretched a little along the z direction. The two

lateral dimensions are optimized by a Monte Carlo procedure every 20 time steps a change in the dimensions is proposed, if the change results in a lower energy it is accepted, otherwise it is discarded.

RESULTS

Figure 1 shows the average stress-strain curves at each grain size. A clear grain size dependence is seen in the maximal flow stress. This figure shows the maximal flow stress and the 0.2% offset yield stress in a standard Hall-Petch plot, i.e. as a function of one over the square root of the grain size. A reverse Hall-Petch effect is clearly seen.



Figure 1 shows the average stress-strain curves at each grain size

In this figure the stacking faults are present in several grains. They are created as partial dislocations (Shockley partials) move through the grains. They would be removed if a second partial dislocation followed in the same plane. This is, however, rarely seen, possibly because the grain size is comparable to the splitting width of the dislocation. Simulations of dislocation emission from a notch in a surface done by Jacobsen and Nielsen (1995) have shown that the leading partial will move several splitting widths away from the notch, before the trailing partial is emitted. Possibly a similar effect is seen here.

We have measured the amount of dislocation activity in the systems. The total dislocation activity is able to explain at most 2-3% plastic deformation, i.e. less than half the observed plastic deformation. To identify the nature of the remaining deformation, we analyzed the relative motion of the individual atoms. Our calculated shows the magnitude of the motion of the atoms obtained by subtracting the coordinates at two different strains (differing by 0.4%). The collective motion due to the imposed strain rate has been subtracted out. It is seen that the motion occurs mainly in the grain boundaries. An indication of the activity in the grain boundaries can also be seen in Fig. 1 when the grain boundaries have become a little thicker during deformation.

CONCLUSIONS

We have demonstrated how atomic-scale simulations can be used to obtain information about the deformation mechanisms in nanocrystalline metals. We find that at these grain sizes the dominating deformation mechanism is sliding in the grain boundaries through a large number of small events in the grain boundary. Each event only involves a few atoms. The result of this large number of small events is a flow in the grain boundaries, permitting the grains to slide past each other with only a minor amount of deformation inside the grains. The deformation mechanism results in a reverse Hall-Petch effect, where the material becomes softer when the grain size is reduced. This is caused by an increase of fraction of the atoms that are in the grain boundaries as the grain size is reduced. We have not yet been able to observe the cross-over between the range of grain sizes where this

deformation mechanism dominates, and grain sizes where a conventional deformation mechanism based on dislocation motion dominates. The hardness and yield stress of nanocrystalline metals is expected to reach its maximum in this cross-over region. In order to simulate larger systems than the ones considered here, the atomic-scale approach must be abandoned. We have provided an overview of simulation techniques at coarser scales, and have indicated how they can be combined with atomic-scale simulations to provide models of the mechanics of metals at multiple length scales. These techniques have not yet become mainstream simulation tools, but it is likely that many of them will gain more widespread usage in the near future.

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